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One-Electron Singular Branch Lines of the Hubbard Chain

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A b stract. { The momentum and energy dependence of the weight distribution in the vicinity of the one-electron spectral-function singular branch lines of the 1D H ubbard model is studied for all values of the electronic density and on-site repulsion U . To achieve this goal we use the recently introduced pseudoferm ion dynam ical theory. Our predictions agree quantitatively for the whole momentum and energy bandwidth with the peak dispersions observed by angle-resolved photoelectron spectroscopy in the quasi-1D organic conductor TTF-TCNQ .

The nite-energy spectral dispersions recently observed in quasi-one-dim ensional (1D) metals by angle-resolved photoelectron spectroscopy (ARPES) reveal signi cant discrepancies from the conventional band-structure description [1,2]. The study of the microscopic mechanisms behind these unusual nite-energy spectral properties remains until now an interesting open problem. There is some evidence that the correlation elects described by the 1D Hubbard model might contain such nite-energy mechanisms [1,2]. However, for nite values of the on-site repulsion U very little is known about its nite-energy spectral properties, in contrast to simpler models [3]. Bosonization [4] and conform ale eld theory [5] do not apply at nite energy. For U! 1 the method of Ref. [6] provides valuable qualitative information, yet a quantitative description of the nite-energy spectral properties of quasi-1D metals requires the solution of the problem for nite values of U. The method of Ref. [7] refers to features of the insulator phase. For U 4t, where t is the transfer integral, there are numerical results for the one-electron spectral function [8] which, unfortunately, provide very little inform ation about the microscopic mechanisms behind the nite-energy spectral properties. Recent prelim inary results obtained by use of the nite-energy holon and spinon description introduced in Refs. [9{11] predict separate one-electron charge and spin spectral branch lines [1]. For the electron-rem oval spectral function these lines show quantitative agreem ent with the peak dispersions observed by ARPES in the quasi-1D organic conductor TTF-TCNQ [1]. However,

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these prelim inary studies provide no information about the momentum and energy dependence of the weight distribution in the vicinity of the charge and spin branch lines and do not describe the TTF dispersion. The main goal of this paper is the evaluation of such a dependence for all values of U and electronic density. In order to solve this complex many-electron problem, we use the pseudoferm ion dynamical theory recently introduced in Ref. [12].

The model reads $\hat{H} = t^F_{j;} [c_{j;}^V c_{j+1}; + h x:] + U^F_{j} \hat{n}_{j;"} \hat{n}_{j;"} \hat{n}_{j;\#}$ where $c_{j;}^V$ and $c_{j;}$ are spin = ";# electron operators at site $j=1; :::; N_a$ and $\hat{n}_{j;}=c_{j;}^V c_{j;}$. The low-energy spectral properties of TTF-TCNQ involve inter-chain hopping and electron-phonon interactions. Thus, our results are to be applied above the energies of these processes. We consider an electronic density $n=N=N_a$ in the range 0 < n < 1 and zero magnetization where N is the electron number. The Fermi momentum is $k_F=n=2$ and the electronic charge reads e. The one-electron spectral function $B^1(k_F;!)$ such that l=1 (and l=+1) for electron removal (and addition) reads, l=10 (k;!) = l=11; l=11, l=12, l=13, l=13, l=14, l=14, l=15, l=15

The pseudoferm ion dynamical theory reveals and characterizes the dominant microscopic processes which generate over 99% of the electronic weight of the functions $B^1(k;!)$, and also describes all other processes [12]. The weight distribution in the vicinity of the branch lines we consider below is fully controlled by such dominant processes. Those involve the 1=2 Yang holons and the co, s1, and c1 pseudoferm ions studied in Ref. [11]. For sim plicity, we denote the rst two objects by c and s pseudoferm ions, respectively. The c pseudoferm ion carries charge e and has no spin and the spseudoferm ion is a spin-zero two-spinon composite object and has no charge. The cl pseudoferm ion is a -spin-zero two-holon composite object, carries charge 2e, and has zero spin. The 1=2 Yang holon has -spin 1=2, -spin projection 1=2, charge 2e, and zero spin. The c, s, and c1 pseudoferm ions carry m om entum q = q + Q $(q)=N_a$, where in our case = c;s;cl. Here q is the bare-m omentum and Q $(q)=N_a$ is a momentum functional de ned in Ref. [11], whose expression involves the two-pseudoferm ion phase shifts $(q;q^0)$ de ned in the same reference, where ; = c;s;c1. Following the one-to-one correspondence between the momentum q and bare-momentum q, one can either label a pseudoferm ion by q or q. Here we use the bare-m om entum q. The above pseudoferm ions have energy bands $_{c}$ (q), $_{s}$ (q), and $_{c1}$ (q) = E $_{u}$ + $_{c1}^{0}$ (q) such that jqj , jqj k_F , and jqj [$2k_{F}$], respectively. These bands are studied and plotted in Ref. [10]. E_{u} de nes the lower-lim it of the upper-Hubbard band (UHB) [9] and equals the energy required for creation of a 1=2 Yang holon, which is a dispersion-less object. It is such that $E_u=4t\cos(n=2)$ for U=t ! 0, E_u = U + 4tcos(n) for U >> t, E_u = U + 4t for n ! 0, and as n ! 1 E_u approaches the value of the M ott-H ubbard gap [10]. In the ground state there are no 1=2 Yang holons, the c1 and s pseudoferm ions bands are empty and lled, respectively, and the c pseudoferm ions occupy 0 jqj $2k_F$ (leaving $2k_F < jqj$ em pty).

The ground state and excited states can be expressed in terms of occupancy congurations of the above quantum objects. For electron removal, the dominant processes involve creation of one hole both in $_{\rm c}$ (q) and $_{\rm s}$ (q). For electron addition, these dominant processes lead to two structures: A lower-Hubbard band (LHB) generated by creation of one particle in $_{\rm c}$ (q) and one hole in $_{\rm s}$ (q); A UHB generated by creation of one hole both in $_{\rm c}$ (q) and either one particle in $_{\rm c1}^{\rm c1}$ (q) for n < 1 or one 1=2 Y ang holon for n ! 1. A coording to the pseudoferm ion dynamical theory of Ref. [12], both the one-electron spectral-weight singularities and edges are located on pseudoferm ion branch lines. Such lines are generated by processes where a

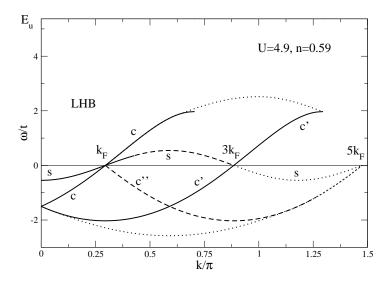


Fig. 1 { Extended-zone scheme centered at k = 0 for $U = 4.9 \, t$ and n = 0.59. The solid and dashed lines denoted by the letters c, c^0 , c^0 , and s are singular and edge branch lines, respectively. Electron removal (LHB addition) corresponds to ! < 0 (and ! > 0) and ! = E_u marks the UHB lower limit.

speci c pseudoferm ion is created or annihilated for the available values of bare-m om entum q and the remaining quantum objects are created or annihilated at their Fermi points. The weight shape of the singular (and edge) branch lines is controlled by negative (and positive) exponents smaller than zero (and one). The electron removal (! < 0) and LHB addition (! > 0) singular and edge branch lines are represented in Fig. 1 by solid and dashed lines, respectively. For simplicity, the gure does not represent the ! > Eu UHB region. (Below we not that the shape of the UHB singular branch lines is fully determined by the shape of the electron-removal singular branch lines represented in Fig. 1.) The dashed-dotted lines and some of the branch lines of Fig. 1 are border lines for the ! < Eu domain of the (k;!) – plane whose spectral weight is generated by dominant processes. (There is a region limited above by the sline for $k_{\rm F}$ < k < 3k_{\rm F} and below by the c^{00} and c^{0} lines for $k_{\rm F}$ < k < 2k_{\rm F} and $2k_{\rm F}$ < k < 3k_{\rm F}, respectively, which does not belong to that domain.) The dominant processes also include particle-hole pseudoferm ion processes which lead to spectral weight both inside and outside but in the close vicinity of that domain.

For simplicity, in this letter we consider the exponents that control the weight shape in the vicinity of singular branch lines only. However, similar expressions can be evaluated for any branch line. The singular branch lines correspond to all the (k;!)-plane regions where there are weight-distribution singularities. While it is dicult to measure the exponents experimentally, a crucial test for the suitability of the model to describe real quasi-1D materials is whether the ARPES peak dispersions correspond to the predicted singular branch lines. The general branch-line spectral-function expression given in Ref. [12] applies provided that the excited states associated with the one-electron branch lines are used.

We start by considering the spin s branch line for $0 < k < 3k_F$, the charge c branch line for $0 < k < k_F$, and the charge c branch line for $0 < k < k_F$ (see Fig. 1). The parametric equations that de ne these branch lines read ! (k) = $_{\rm S}$ (q) for the s line where $q = q(k) = (1+1)k_F$ lk for $(1+1)k_F = 2 < k < k_F + (1+1)k_F$ and ! (k) = (q) for the = c line ($^0 = +1$) and = c^0 line ($^0 = -1$) where $q = q(k) = k + {^0}k_F$ for $0 < k < {^0}k_F$.

Here, l=1 and $_{c^0}(q)$ $_{c}(q)$. The following expression describes the weight distribution in the vicinity of the =s; c; c^0 branch lines for ! values such that ((q) + 1!) is small and positive,

$$B^{1}(k;!) = C^{1}(k)$$
 (q) + 1! ; = s;c;c⁰: (1)

The k-dependence of $C^1(k)$, such that $C^1(k) > 0$ for U = t > 0, is in general involved and can be studied numerically. For U = t ! 0, $C^1(k)$ behaves as $C_s^1(k) ! _{1; 1} C_s$, $C_c^1(k) ! _{1; +1} C_c$, and $C_{c^0}(k) ! 0$, where C_s and C_c are independent of k. The exponent of Eq. (1) reads,

$$(k) = 1 + \begin{cases} x & \text{hn} & \frac{1}{2^{\frac{n}{2}}} \\ & 1 + \frac{1}{2^{\frac{n}{2}}} \end{cases}$$

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where = c for 0 = +1, = c^{0} for 0 = 1, and $f_{1}(x)$ = 1 1(1 + x). In equation (2) the phase shifts are dened in Ref. [11] and $_{
m 0}$ $\overline{2K}$ where K , such that K ! 1 as U=t ! 0 and K ! 1=2 as U=t ! 1 , is de ned in Ref. [4]. The exponents $_{\rm s}$ (k) and $= cic^{\circ}(k)$ are plotted in Figs. 2 and 3, respectively, as a function of k for several values of U=t and n=0.59. The exponent $_{c}$ (k) (and $_{c^{0}}$ (k)) is plotted in Fig. 3 (a) and (b) (and Fig. 3 (c) and (d)) for l = 1 and l = +1, respectively. As U=t ! 1 these exponents behave as $_{s}(k) = 1 = 2 + 2(q = 4k_{F})^{2}$ and $_{s}(k) = (q = 2k_{F})[1 (q = 4k_{F})]$ for l = 1 and l = +1, respectively, and $_{c}(q) = _{c^{0}}(q) = _{3=8}$, in agreem ent with Ref. [6]. The weight shape of the UHB singular branch lines is controlled by the same exponents as the corresponding electronrem oval branch lines. There is a UHB s_u branch line for $k_F < k < , c_u$ branch line for $k_{\rm F}$ < k < $\,$, and c $^{\!0}_{\rm u}$ branch line for $\,$ 3 $k_{\rm F}$ < k < $\,$. For 0 < k < $\,$ and ! > E $_{\rm u}$ the param etric equations of these lines is the same as for the corresponding s, c, and c^0 branch lines, respectively, provided that k is replaced by k and ! by E_u ! in the parametric equations of the latter lines. Under such a replacem ent the exponents that control the weight shape of these UHB lines are the same as for the corresponding electron-rem oval lines. While in the lim it n! 1 such a correspondence refers also to the value of the constant C 1 (k) of Eq. (1), otherwise the corresponding UHB constant C^{+1} (k) is slightly smaller. This is because for n < 1 there is also weight in the vicinity of four UHB c1 pseudoferm ion branch lines. We om it here the study of the weight shape of these lines whose exponents are positive. When the exponents (2) tend to 1 as U = t! 0 the expression (1) is replaced by ((q)+ 1!). For 0 < k < and U = t! 0 all spectral weight is transferred over to the s branch line for $0 < k < k_F$, c branch line for $k_F < k < k_F$, and s_u branch line for $k_F < k < .$ There is no weight in other branch lines and k > 0 regions of the (k; !)-plane in such a lim it. The two points (k = k_F ; ! = E_u) and ($k = k_F$; ! = $_c$ ()) where q = corresponds to k_F become the same point as U=t! 0 and the cand s_u branch lines become connected k =at that point. By use of the U=t! 0 expressions given in Ref. [10] for $_{c}$ (q) and $_{s}$ (q), one nds that these three branch lines give rise to the electronic spectrum $!(k) = 2t[\cos(k) \cos(k_F)]$. C onsistently, the above corresponding exponents are such that $_{\rm s}$ (k) ! 1 for 0 < k < k_{\rm F} , $_{c}(k)$! 1 for $k_{F} < k <$ k_F , and s_m (k) = s(k)! 1 for $k_F < k < as$ U=t! 0. Then the correct non-interacting electronic spectral function is reached as U=t! 0. (For U = t! 0 the exponents (2) behave as $_{s}$ (k) = 1 = 1, (q) = $1 = \frac{1}{2} + 1 = 2$ for = $c_{i}c^{0}$

and l = 1, and $_{c}(q) = 1$ and $_{c^{0}}(q) = 1$ for l = +1.)

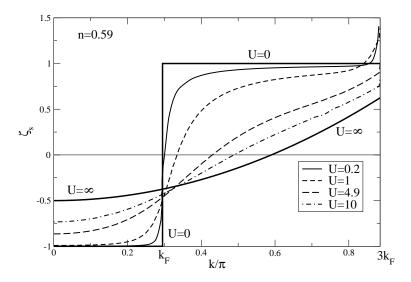


Fig. 2 { Momentum dependence along the spin s branch line of the exponent (2).

We note that for (k;!) points in the vicinity of the branch-line end points $(k_0; jE_u)$ where j = 0 for $= s; c; c^0$ and j = 1 for $= s_u; c_u; c^0_u$, respectively, the spectral-function expression (1) remains valid provided that the exponent (k) given in Eq. (2) is replaced 2 ¹(k) for! $l(q(k)) = lv(k k_0) + jE_u$. Here l = 1 (k) is a functional dened in Ref. [12]. v = 0 (q) = 0 $q_{q=q_F}$, $q_{Fc} = 2k_F$, $q_{Fs} = k_F$, and 2 (In Fig. 1, $k_0 = k_F$, $k_0 = 3k_F$, and $k_0 = 5k_F$ for j = 0.) For j = 0 this lim it corresponds to the so called low-energy Tom anaga-Luttinger liquid regime and the above exponent (k) equals that given in Eq. (5.7) of Ref. [5]. The branch-line k dom ain corresponding to that exponent has zero m easure relative to the k dom ain of the branch-line exponent (k). Therefore, in this paper we do not consider such a lim iting regime. A nother case of the interest is the behavior of the spectral function in the vicinity of the end points $(k_0; jE_u)$ when these points are approached by lines which do not cross the branch lines. In this case the weightdistribution is controlled by an exponent dierent from both (k) and

An interesting realization of a 1D metal is the organic charge-transfer salt TTF-TCNQ [2]. The experim ental dispersions in the electron rem oval spectrum of this quasi-1D conductor as measured by ARPES are shown in Fig. 4. The data were taken with He I radiation (212 eV) at a sample temperature of 60 K on a clean surface obtained by in situ cleavage of a single crystal. Instrumental energy and momentum resolution amount to 70 meV and 0.07 A 1, respectively. The experimental data in Fig. 4 reproduce earlier work [1,2]. While our above theoretical weight-distribution expressions refer to all values of U=t and n, we nd that the electron rem oval spectra calculated for t = 0.4 eV, U = 1.96 eV (U = t = 0.49), and n = 0.59 yields an alm ost perfect agreem ent with the three TCNQ experim ental dispersions. The exception is the low-energy behavior, as a result of the inter-chain hopping and electronphonon interactions, as m entioned above. If accounted for a renorm alization of the transfer integral due to a possible surface relaxation [1], these values are in good agreement with estim ates from other experim ents [2]. The experim ental TCNQ nite-energy peak dispersions of Fig. 4 correspond to the spin s branch line and charge c and c^0 branch lines. Im portantly, only these singular branch lines, whose weight shape is controlled by negative exponents, lead to peak dispersions in the real experiment. The other peak dispersion of Fig. 4 is associated

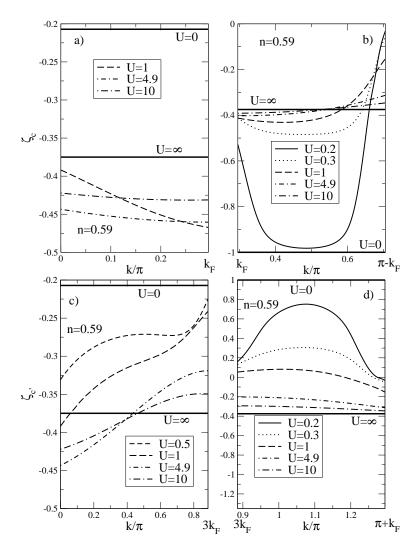


Fig. 3 { Momentum dependence of the exponent (2) along (a) and (c) the electron-rem oval and (b) and (d) electron-addition charge c and c^0 branch lines, respectively.

with the electron-rem oval spectrum of the TTF chains whose density is n=2 0.59=1.41. It can be described by the electron-addition spectrum of a corresponding n=0.59 problem . Rem arkably, we $\,$ nd again that the theoretical lines m atch the TTF dispersion provided that to 0.27 eV and U <0.2t within experimental uncertainty. Indeed, for such small values of U=t and n=0.59 both the electron-addition exponents of Figs. 2 and 3 (d) are positive, whereas the exponent of Fig. 3 (b) and the UHB exponent $_{\rm Su}$ (k) = $_{\rm S}$ (k) for $_{\rm K}<$ k_F (see Fig. 2) are negative. For n=1.41 the c and su lines associated with these exponents correspond to electron removal and thus appear at negative values of ! and lead to a single singular branch line formed by the cline for 0.59 =2 < k < 1.41 =2 and the su line for 1.41 =2 < k < . The energy pseudogap at k = 1.41 =2, which separates the cline from the su line, nearly vanishes for U=t < 0.2t and thus is not observed in the experiment. This singular branch line is that matching the TTF peak dispersion of Fig. 4. (It matches such

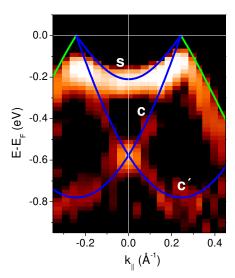


Fig. 4 { Angle-resolved photoem ission spectra of TTF-TCNQ measured along the easy transport axis and matching theoretical branch lines.

a dispersion for 0.59 = 2 < k < ...) We thus conclude that in contrast to the conventional band structure description, the singular branch lines obtained from the 1D Hubbard model describe quantitatively, for the whole nite-energy band width, the peak dispersions observed by ARPES in TTF-TCNQ. This seems to indicate that the dominant non-perturbative many-electron microscopic processes described by the pseudoferm ion dynamical theory of Ref. [12], which control the weight distribution of these charge and spin singular branch lines, also control the unusual nite-energy one-electron spectral properties of TTF-TCNQ.

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